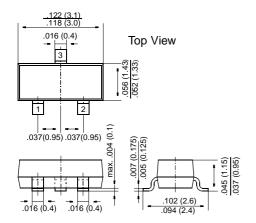
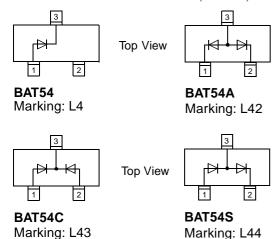
BAT54 THRU BAT54S

Schottky Diodes

SOT-23

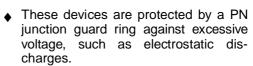


Dimensions in inches and (millimeters)



FEATURES

◆ These diodes feature very low turn-on voltage and fast switching.





MECHANICAL DATA

Case: SOT-23 Plastic Package **Weight:** approx. 0.008 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS FOR ONE DIODE

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	30	V	
Forward Continuous Current at T _{amb} = 25 °C	IF	2001)	mA	
Repetitive Peak Forward Current at T _{amb} = 25 °C	I _{FRM}	3001)	mA	
Surge Forward Current at t _p < 1 s, T _{amb} = 25 °C	I _{FSM}	6001)	mA °C	
Junction Temperature	Tj	150		
Storage Temperature Range	T _S	-65 to +150	°C	
1) Device on fiberglass substrate, see layout.	1		-	

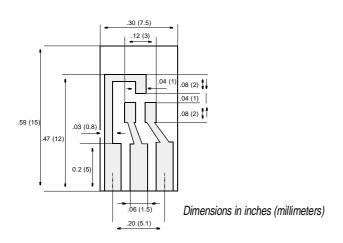


BAT54 THRU BAT54S

ELECTRICAL CHARACTERISTICS

Ratings for one diode at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage tested with 100 μA Pulses	V _{(BR)R}	30	-	-	V
Forward Voltage Pulse Test $t_p < 300 \mu s$, $\delta < 2\%$ at $I_F = 0.1 mA$ at $I_F = 1 mA$ at $I_F = 10 mA$ at $I_F = 30 mA$ at $I_F = 100 mA$ at $I_F = 100 mA$	V _F V _F V _F V _F	- - - -	- - - - -	240 320 400 500 1000	mV mV mV mV
Pulse Test t_p < 300 μ s, δ < 2% at V_R = 25 V					
Capacitance at V _F = 1 V, f = 1 MHz	C _{tot}	_	_	10	pF
Reverse Recovery Time from I_F = 10 mA to I_R = 1 mA, I_L = 100 I_R	t _{rr}	_	-	5	ns
Thermal Resistance Junction to Ambient Air	R _{thJA}	_		4301)	K/W



Layout for R_{thJA} test

Thickness: Fiberglass 0.059 in (1.5 mm) Copper leads 0.012 in (0.3 mm)

